2A, 50V - 1000V Surface Mount Fast Recovery Rectifiers

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Glass passivated junction chip.
- Fast switching for high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- AEC-Q101 qualified

DO-214AA (SMB)

Pb-Free

RoHS COMPLIANT

MECHANICAL DATA

Case: DO-214AA (SMB)

Molding compound, UL flammability classification rating 94V-0

Packing code with suffix "G" means green compound (halogen-free)

Moisture sensitivity level: level 1, per J-STD-020

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: Indicated by cathode band

Weight: 0.09 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	RS 2A	RS 2B	RS 2D	RS 2G	RS 2J	RS 2K	RS 2M	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	$I_{F(AV)}$	2							A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	50							A
Maximum instantaneous forward voltage (Note 1) I_F= 2 A	V_F	1.3							V
Maximum reverse current @ rated VR T_J=25 °C T_J=125 °C	I_R	5 50							μA
Maximum reverse recovery time (Note 2)	t_{rr}	150				250	500		ns
Typical junction capacitance (Note 3)	C_J	50							pF
Typical thermal resistance	$R_{\theta JL}$ $R_{\theta JA}$	18 55							°C/W
Operating junction temperature range	T_J	- 55 to +150							°C
Storage temperature range	T_{STG}	- 55 to +150							°C

Note 1: Pulse test with PW=300μs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

Note 3: Measured at 1 MHz and Applied V_R=4.0 Volts

ORDER INFORMATION (EXAMPLE)

RS2A R5G

- Green compound code
- Packing code
- Part no.

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

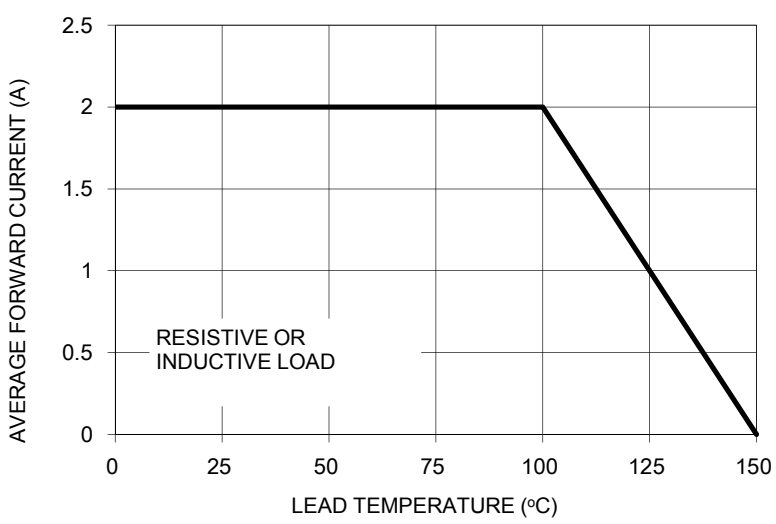


FIG. 2 TYPICAL REVERSE CHARACTERISTICS

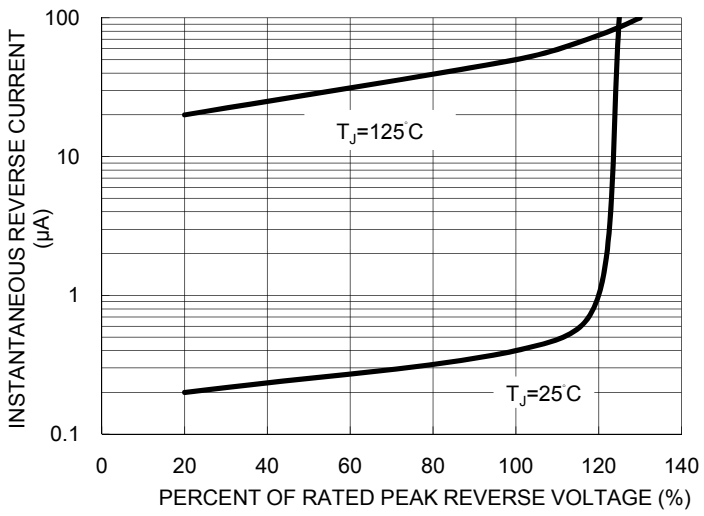


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

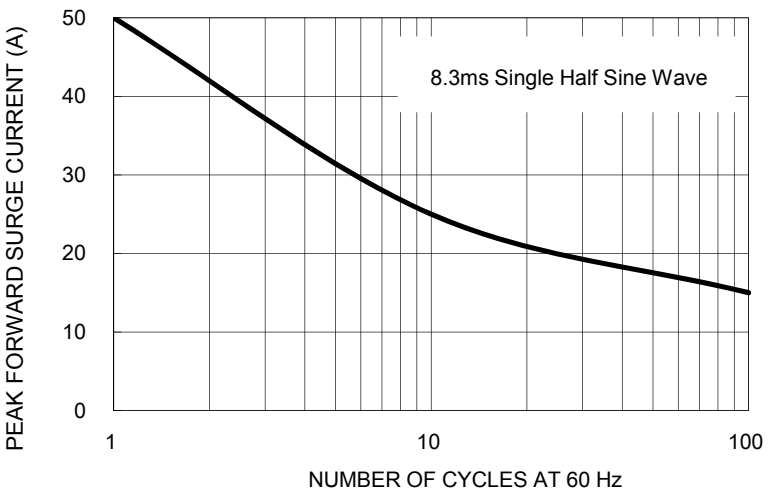


FIG. 4 TYPICAL FORWARD CHARACTERISTICS

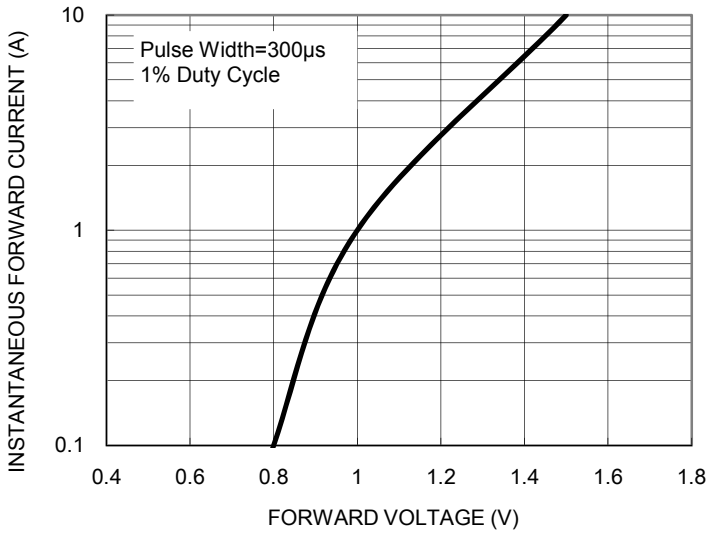


FIG. 5 TYPICAL JUNCTION CAPACITANCE

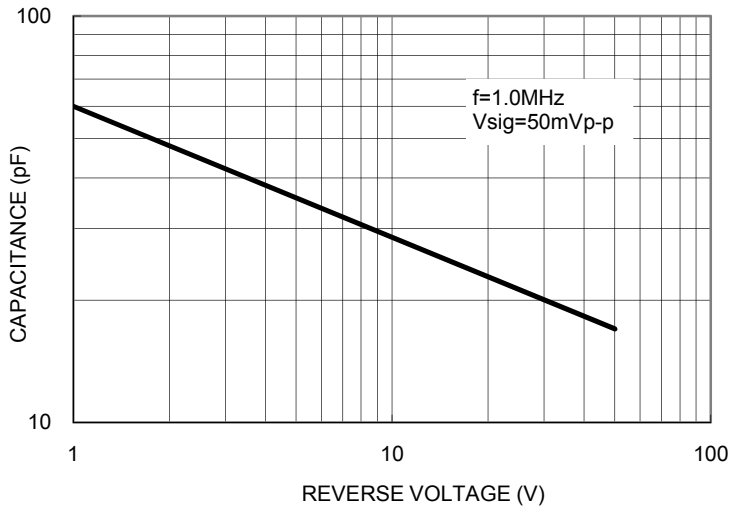
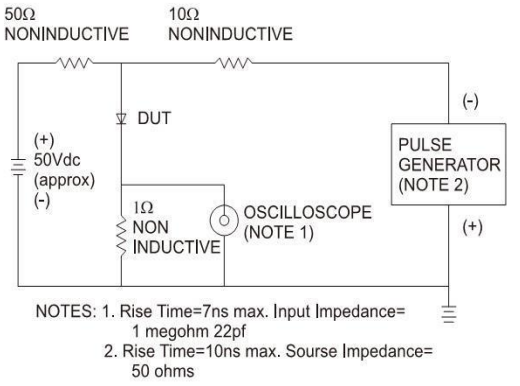
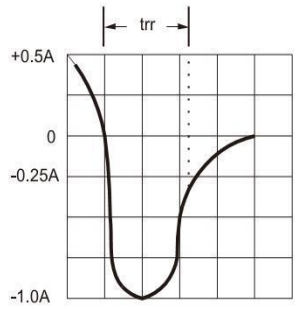


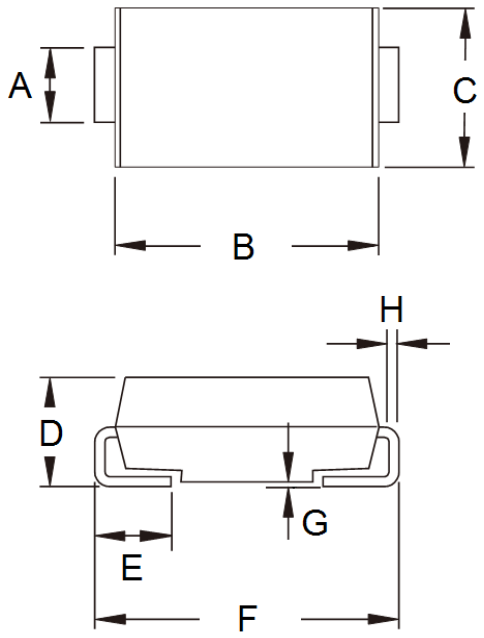
FIG.6 REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM





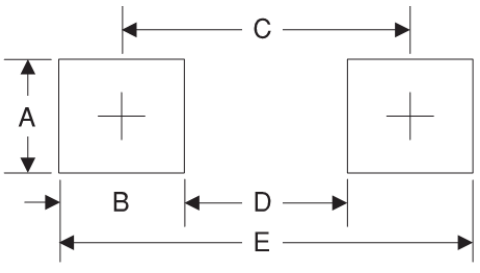
PACKAGE OUTLINE DIMENSIONS

DO-214AA (SMB)



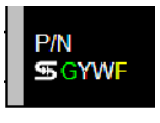
DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.95	2.10	0.077	0.083
B	4.25	4.75	0.167	0.187
C	3.48	3.73	0.137	0.147
D	1.99	2.61	0.078	0.103
E	0.90	1.41	0.035	0.056
F	5.10	5.30	0.201	0.209
G	0.10	0.20	0.004	0.008
H	0.15	0.31	0.006	0.012

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	2.3	0.091
B	2.5	0.098
C	4.3	0.169
D	1.8	0.071
E	6.8	0.268

MARKING DIAGRAM



P/N = Specific Device Code
G = Green Compound
YW = Date Code
F = Factory Code

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